
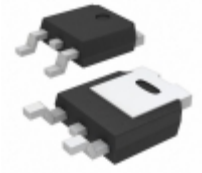

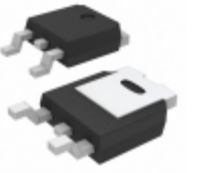
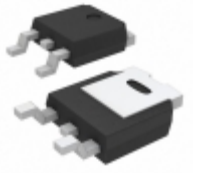

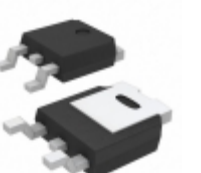
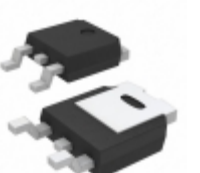
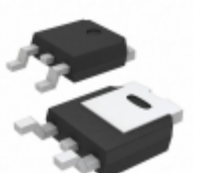
 life.augmented	<h2>STD11NM60N</h2>
	<p>Hersteller-Teilenummer: STD11NM60N</p> <p>Hersteller / Marke: STMicroelectronics</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 10A DPAK</p> <p>Datenblätter:  STD11NM60N.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7745 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD11NM60N
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 600V 10A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	7745 pcs Stock
Serie	MDmesh™ II
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	90W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10A (Tc)
Rds On (Max) @ Id, Vgs	450 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	31nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	850pF @ 50V
Verpackung	Tape & Reel (TR)



















































STD11NM60N ist neu im Original, Suche STD11NM60N Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD11NM60N STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD11NM60N: Info@Y-IC.com

Sie können auch interessiert sein:

 STD120N4F6 STMicroelectronics MOSFET N-CH 40V 80A DPAK	 STD11N65M5 11NM65 ST STD11N65M5 11NM65 ST	 STD11NM65N STMicroelectronics MOSFET N CH 650V 11A DPAK	 STD11NM60ND STMicroelectronics MOSFET N-CH 600V 10A DPAK
 STD11NM65M5 11N65 TO-252 STD11NM65M5 11N65 TO-252	 STD11N65M2 STMicroelectronics MOSFET N-CH 650V 7A DPAK	 STD11N65M5 STMicroelectronics MOSFET N CH 650V 9A DPAK	 STD11NM50N STMicroelectronics MOSFET N-CH 500V 9A DPAK

heiße Teile

Mehr

 STD10NM60N	 STD10NM60ND	 STD10NM65N	 STD10P10F6	 STD10P6F6
 STD10PF06	 STD10PF06-1	 STD10PF06L	 STD10PF06T4	 STD110N8F6
 STD110NH02LT4	 STD116GK08	 STD116GK08B	 STD116GK12	 STD116GK12B
 STD116GK14	 STD116GK14B	 STD116GK16	 STD116GK16B	 STD116GK18
 STD116GK18B	 STD11N50M2	 STD11N65M2	 STD11N65M5	 STD11NM50N
 STD11NM60ND	 STD120N4F6	 STD120N4LF6	 STD123SF	 STD123UF
 STD125GK16	 STD12L01	 STD12L01A	 STD12N05LT4	 STD12N06
 STD12N06L	 STD12N06LT4	 STD12N06T4	 STD12N10L	 STD12N10L-TR
 STD12N50M2	 STD12N60M2	 STD12N65M5	 STD12NE06	 STD12NE06L-TR
 STD12NE06LT4	 STD12NE06T4	 STD12NF06-1	 STD12NF06L-1	 STD12NF06LT4

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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